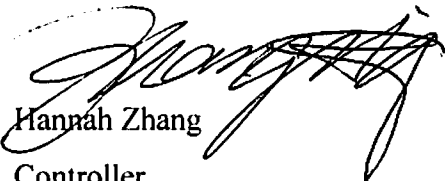


Product Change Notification

Manufacturer : GeneSiC Semiconductor Inc.
PCN No. : 1804 SiC SJT
Affected Parts : See Appendix A
Date of Issue : April 27, 2018
Title of Change : Pre-2013 SiC Junction Transistors - Partial
Type of Change : End of Life
Last Time Buy Date : N/A
Change Description : Elimination of Products from GeneSiC Product Portfolio
Reason for Change : SiC SJTs are progressively replaced by SiC MOSFETs by most customers
Manufacturer Contact :
Email ID : sales@genesicsemi.com
Signature : 
Name : Hannah Zhang
Title : Controller

Reference To Change Types:

- End of Life
- Fabrication Site Change / Qualification / Country of Origin / New Subcontractor
- Cosmetic Change
- Name Change
- Nomenclature Change
- Product Family Change
- Product Series Change

APPENDIX A

AFFECTED PARTS NUMBERS

Product Family/Category: SiC Junction Transistors

Product Name	Category	V	A	Rds	Pkg Styl
GA03JT12-247	SiC Junction Transistor	1200	3	470mO	TO-247
GA05JT12-247	SiC Junction Transistor	1200	15	260mO	TO-247
GA06JT12-247	SiC Junction Transistor	1200	6	220mO	TO-247
GA10JT12-247	SiC Junction Transistor	1200	25	130mO	TO-247
GA20JT12-247	SiC Junction Transistor	1200	45	65mO	TO-247
GA50JT12-263	SiC Junction Transistor	1200	100	25mO	TO-263
GA16JT17-247	SiC Junction Transistor	1700	45	110mO	TO-247
GA50JT17-247	SiC Junction Transistor	1700	100	25mO	TO-247

Product Family/Category: High Temperature SiC Junction Transistors

Product Name	Category	V	A	Temp-erature	Rds	Pkg Styl
2N7635-GA	SiC High Temperature JT	650	4	225	425mO	TO-257 Herm Pkg
2N7636-GA	SiC High Temperature JT	650	4	225	425mO	SMD0.5/TO-276Herm Pkg
2N7637-GA	SiC High Temperature JT	650	7	225	170mO	TO-257 Herm Pkg
2N7638-GA	SiC High Temperature JT	650	8	225	180mO	SMD 0.5 /TO-276 Herm Pkg
2N7639-GA	SiC High Temperature JT	650	15	225	65mO	TO-257 Herm Pkg
2N7640-GA	SiC High Temperature JT	650	16	225	110mO	SMD0.5/TO-267 Herm Pkg